

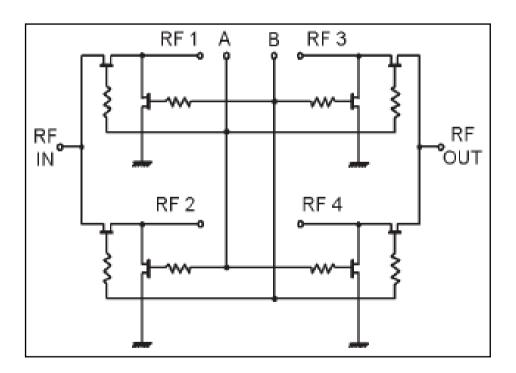
## **Product Description**

The RBS641 is a high performance Gallium Arsenide Double pole double throw broad band RF switch. It is suitable for use in broadband communications and instrumentation applications. A short circuit reflective termination is presented at the isolated outputs of the switch. The switch is controlled by the application of complimentary OV/-5V or O/-8V signals to the control lines in accordance with the truth table below.

### Features

- Broadband performance
- Low Insertion Loss; 0.6 dB typ at 2 GHz
- Ultra low DC power consumption

## **Functional Block Diagram**





# Specifications Absolute Maximum Ratings

Name	Description	
Max Control Voltage	-8 V	
RF I/P Power	RF I/P Power +30 dBm	
Operating Temperature Range	perating Temperature Range -40 to +85° C	

## **Electrical Performance**

# Typical performance at 25°C

Ambient temperature =  $25\pm3^{\circ}$ C, Zo =  $50 \Omega$ , Control voltage = 0V/-5V unless otherwise stated

Parameter	Condition	Min.	Тур.	Max.	Units
Insertion Loss <sup>1</sup>	DC – 3 GHz	-	0.57	0.6	dB
	3 – 6 GHz	-	0.85	0.9	dB
Isolation <sup>1</sup>	DC – 3 GHz	68	70	-	dB
	3 – 6 GHz	63	64	-	dB
Input Return Loss <sup>2</sup>	DC – 3 GHz	25	29	-	dB
	3 – 6 GHz	16	25	-	dB
Output Return Loss <sup>2</sup>	DC – 3 GHz	25.6	28	-	dB
	3 – 6 GHz	18	25	-	dB
P1dB power compression point <sup>3</sup>	0/-5 V control; 50 MHz -		19.5	-	dBm
	0/-5 V control; 0.5 - 4 GHz -		25.5	-	dBm
	0/-8 V control; 50 MHz	-	21.5	-	dBm
	0/-8 V control; 0.5 - 4GHz	-	28	-	dBm
Switching Speed	50% control to 10%90% RF	-	2.2	-	ns

#### Notes

- 1. Insertion loss and Isolation measured between RF Input and any output.
- 2. Return Loss measured in low loss switch state.
- 3. Input power at which insertion loss compresses by 1dB.



RBS641 GAAS MMIC DPDT REFLECTIVE SWITCH, DC -

# **Preliminary Data**

0

-10

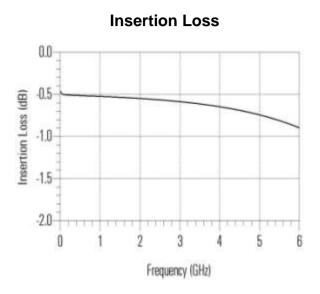
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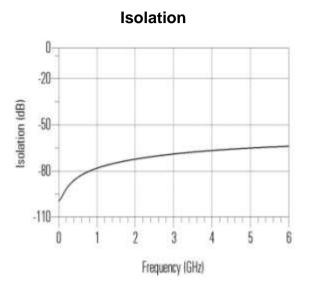
-30

-40-

0

Return Loss (dB)





Input Return Loss

2

3

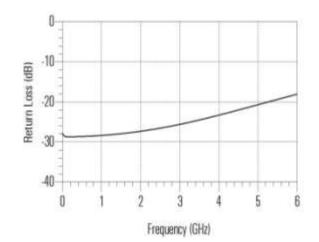
Frequency (GHz)

Δ

5

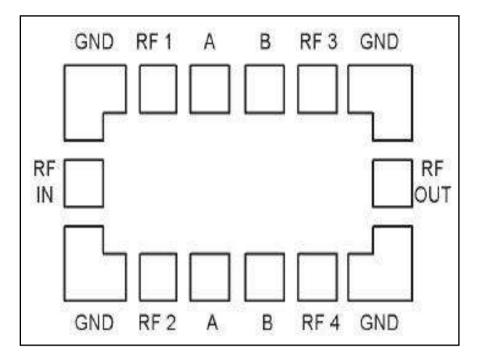
6

Output Return Loss





# Chip Outline Diagram



Die size: 1.2 X 1.5 mm Minimum Bond pad size: 120  $\mu m$  x 120  $\mu m$  Die thickness: 200  $\mu m$ 

# Switching Truth Table

Α	В	RF IN-RF1	RF IN-RF2	
		RF3-RF OUT	RF4-RF OUT	
0 V	-5 V	Low Loss	Isolated	
-5 V	0 V	Isolated	Low Loss	



RBS64

### http://www.rfarrays.com

### **Customer Service Locations**

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#### **Product Preview**

The document contains information from the product concept specification. RF Arrays Inc. reserves the right to change information at any time without notification.

### Preliminary Information

The document contains information from the design target specification. RF Arrays Inc. reserves the right to change information at any time without notification.

#### Production testing may not include testing of all parameters.

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